SN74LS85(LX)
4-bit Magnitude Comparator

Product Specification

Specification Revision History:

Version	Date	Description
2022-06-A1	2022-06	New
2023-04-B1	2023-04	Update the template

Contents

1、General Description

The SN74LS85 is a 4-bit magnitude comparator that can be expanded to almost any length. They perform comparison of two 4-bit binary, BCD or other monotonic codes and present the three possible magnitude results at the outputs ($Q_{A>B}$, $Q_{A=B}$ and $Q_{A<B}$). The 4-bit inputs are weighted (A0 to A3 and B0 to B3), where A3 and B3 are the most significant bits. For proper compare operation the expander inputs ($I_{A>B}$, $I_{A=B}$ and $I_{A<B}$) to the least significant position must be connected as follows: $I_{A<B}$=$I_{A>B}$=LOW and $I_{A=B}$=HIGH. For words greater than 4-bits, units can be cascaded by connecting outputs $Q_{A>B}$, $Q_{A=B}$ and $Q_{A<B}$ to the corresponding inputs of the significant comparator. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features:

- CMOS low power dissipation
- Specified from -40℃ to +125℃
- Packaging information: DIP16/SOP16/TSSOP16

Ordering Information:

Tube packing specifications:

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
SN74LS85N(LX)	DIP16	SN74LS85N	25 PCS/tube	40 tube/box	1000 PCS/box	Dimensions of plastic enclosure: 19.0mm×6.4mm Pin spacing: 2.54mm
SN74LS85DR(LX)	SOP16	LS85	50 PCS/tube	200 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing: 1.27mm
SN74LS85PW(LX)	TSSOP16	LS85	96 PCS/tube	200 tube/box	19200 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
SN74LS85DR(LX)	SOP16	LS85	2500 PCS/reel	5000 PCS/box	Dimensions of plastic enclosure: 10.0mm×3.9mm Pin spacing:1.27mm
SN74LS85PW(LX)	TSSOP16	LS85	5000 PCS/reel	10000 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing:0.65mm

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.

2、Block Diagram And Pin Description

2.1、Block Diagram

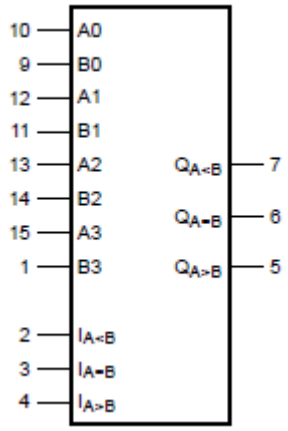


Figure 1. Logic symbol

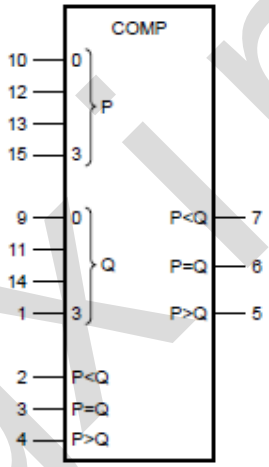


Figure 2. IEC logic symbol

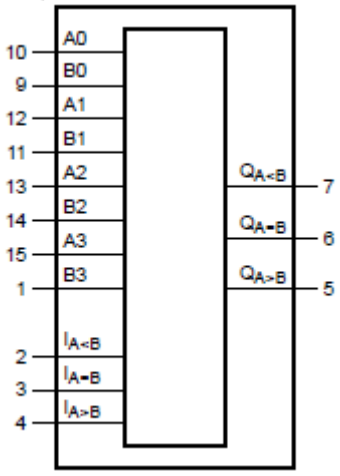


Figure 3. Functional diagram

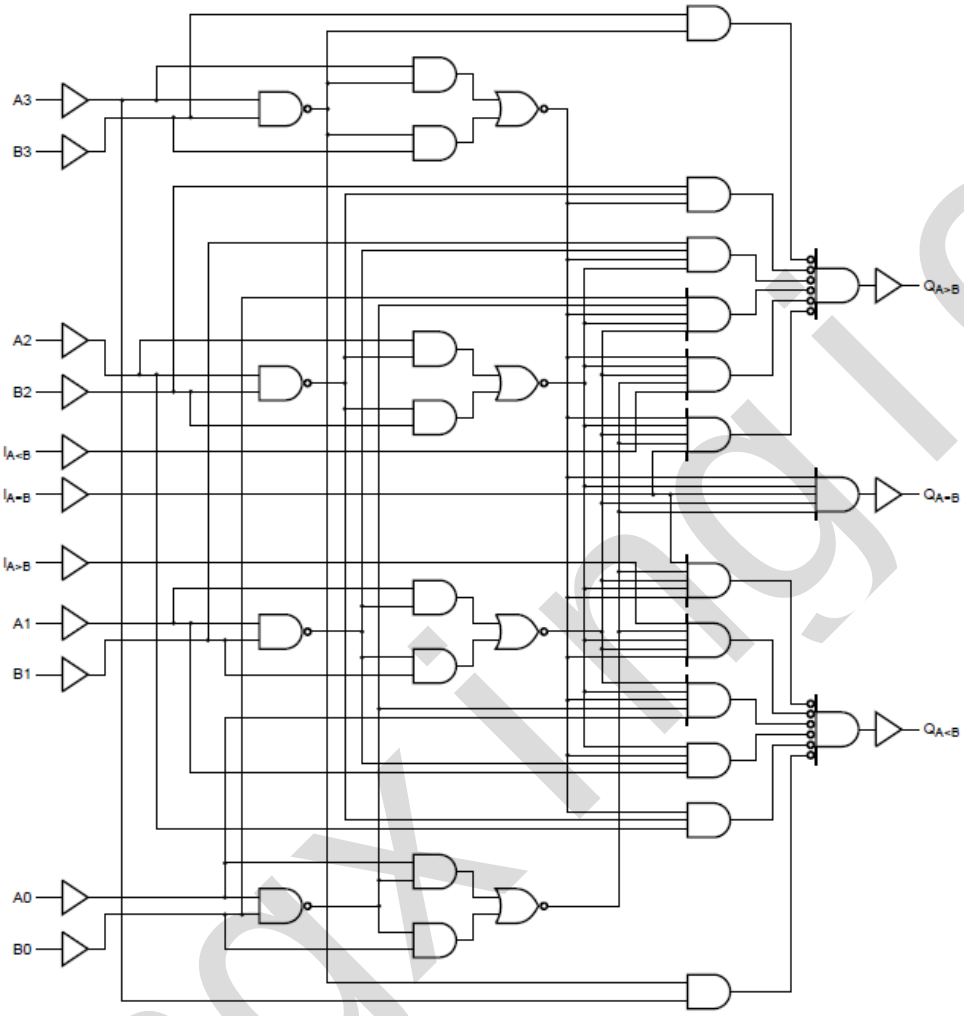
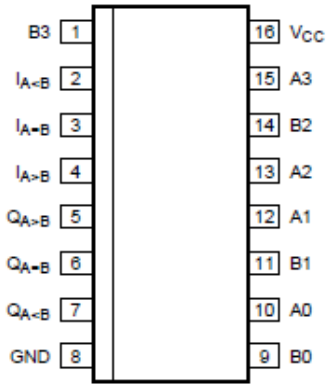


Figure 4. Logic diagram

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	B3	word B input
2	$I_{A<B}$	A<B expansion input
3	$I_{A=B}$	A=B expansion input
4	$I_{A>B}$	A>B expansion input
5	$Q_{A>B}$	A>B output
6	$Q_{A=B}$	A=B output
7	$Q_{A<B}$	A<B output
8	GND	ground (0V)
9	B0	word B input
10	A0	word A input
11	B1	word B input
12	A1	word A input
13	A2	word A input
14	B2	word B input
15	A3	word A input
16	V_{CC}	supply voltage

2.4、Function Table

Comparing input				Cascading input			Output		
A3, B3	**A2, B2**	**A1, B1**	**A0, B0**	**$I_{A>B}$**	**$I_{A<B}$**	**$I_{A=B}$**	**$Q_{A>B}$**	**$Q_{A<B}$**	**$Q_{A=B}$**
A3>B3	X	X	X	X	X	X	H	L	L
A3<B3	X	X	X	X	X	X	L	H	L
A3=B3	A2>B2	X	X	X	X	X	H	L	L
A3=B3	A2<B2	X	X	X	X	X	L	H	L
A3=B3	A2=B2	A1>B1	X	X	X	X	H	L	L
A3=B3	A2=B2	A1<B1	X	X	X	X	L	H	L
A3=B3	A2=B2	A1=B1	A0>B0	X	X	X	H	L	L
A3=B3	A2=B2	A1=B1	A0<B0	X	X	X	L	H	L
A3=B3	A2=B2	A1=B1	A0=B0	H	L	L	H	L	L
A3=B3	A2=B2	A1=B1	A0=B0	L	H	L	L	H	L
A3=B3	A2=B2	A1=B1	A0=B0	L	L	H	L	L	H
A3=B3	A2=B2	A1=B1	A0=B0	X	X	H	L	L	H
A3=B3	A2=B2	A1=B1	A0=B0	H	H	L	L	L	L
A3=B3	A2=B2	A1=B1	A0=B0	L	L	L	H	H	L

Note: H=HIGH voltage level; L=LOW voltage level; X=don’t care.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V_{CC}	-		-0.5	+7.0	V
input clamping current	I_{IK}	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$		-	±20	mA
output clamping current	I_{OK}	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$		-	±20	mA
output current	I_O	$-0.5V < V_O < V_{CC}+0.5V$		-	±25	mA
supply current	I_{CC}	-		-	50	mA
ground current	I_{GND}	-		-50	-	mA
storage temperature	T_{stg}	-		-65	+150	℃
total power dissipation	P_{tot}	-		-	500	mW
soldering temperature	T_L	10s	DIP	245		℃
			SOP/TSSOP	260		

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	2.0	5.0	6.0	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	Δt/ΔV	V_{CC}=2.0V	-	-	625	ns/V
		V_{CC}=4.5V	-	1.67	139	ns/V
		V_{CC}=6.0V	-	-	83	ns/V
ambient temperature	T_{amb}	-	-40	-	+125	℃

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

(T_{amb}=25℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	1.2	-	V
		V_{CC}=4.5V		3.15	2.4	-	V
		V_{CC}=6.0V		4.2	3.2	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	0.8	0.5	V
		V_{CC}=4.5V		-	2.1	1.35	V
		V_{CC}=6.0V		-	2.8	1.8	V
HIGH-level output voltage	V_{OH}	V_I=V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	2.0	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	4.5	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	6.0	-	V
			I_O=-4.0mA; V_{CC}=4.5V	3.98	4.32	-	V
			I_O=-5.2mA; V_{CC}=6.0V	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	V_I=V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	0	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	0	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	0	0.1	V
			I_O=4.0mA; V_{CC}=4.5V	-	0.15	0.26	V
			I_O=5.2mA; V_{CC}=6.0V	-	0.16	0.26	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	8.0	uA
input capacitance	C_I	-		-	3.5	-	pF

3.3.2、DC Characteristics 2

(T_{amb}=-40℃ to +85℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	-	-	V
		V_{CC}=4.5V		3.15	-	-	V
		V_{CC}=6.0V		4.2	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	-	0.5	V
		V_{CC}=4.5V		-	-	1.35	V
		V_{CC}=6.0V		-	-	1.8	V
HIGH-level output voltage	V_{OH}	V_I=V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	-	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	-	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	-	-	V
			I_O=-4.0mA; V_{CC}=4.5V	3.84	-	-	V
			I_O=-5.2mA; V_{CC}=6.0V	5.34	-	-	V
LOW-level output voltage	V_{OL}	V_I=V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	-	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	-	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	-	0.1	V
			I_O=4.0mA; V_{CC}=4.5V	-	-	0.33	V
			I_O=5.2mA; V_{CC}=6.0V	-	-	0.33	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	80	uA

3.3.3、DC Characteristics 3

(T_{amb}=-40℃ to +125℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	-	-	V
		V_{CC}=4.5V		3.15	-	-	V
		V_{CC}=6.0V		4.2	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	-	0.5	V
		V_{CC}=4.5V		-	-	1.35	V
		V_{CC}=6.0V		-	-	1.8	V
HIGH-level output voltage	V_{OH}	V_I=V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	-	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	-	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	-	-	V
			I_O=-4.0mA; V_{CC}=4.5V	3.7	-	-	V
			I_O=-5.2mA; V_{CC}=6.0V	5.2	-	-	V
LOW-level output voltage	V_{OL}	V_I=V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	-	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	-	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	-	0.1	V
			I_O=4.0mA; V_{CC}=4.5V	-	-	0.4	V
			I_O=5.2mA; V_{CC}=6.0V	-	-	0.4	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	160	uA

3.3.4、AC Characteristics 1

(T_{amb}=25℃, GND =0V, C_L=50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
SN74LS85							
propagation delay	t_{pd}	An, Bn to $Q_{A>B}$; An, Bn to $Q_{A<B}$; see Figure 6[1]	V_{CC}=2.0V	-	63	195	ns
			V_{CC}=4.5V	-	23	39	ns
			V_{CC}=5.0V; C_L=15pF	-	20	-	ns
			V_{CC}=6.0V	-	18	33	ns
		An, Bn to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	58	175	ns
			V_{CC}=4.5V	-	21	35	ns
			V_{CC}=5.0V; C_L=15pF	-	18	-	ns
			V_{CC}=6.0V	-	17	30	ns
		$I_{A=B}$ or $I_{A>B}$ to $Q_{A<B}$; $I_{A<B}$ or $I_{A=B}$ to $Q_{A>B}$; see Figure 6	V_{CC}=2.0V	-	50	140	ns
			V_{CC}=4.5V	-	18	28	ns
			V_{CC}=5.0V; C_L=15pF	-	15	-	ns
			V_{CC}=6.0V	-	14	24	ns
		$I_{A=B}$ to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	39	120	ns
			V_{CC}=4.5V	-	14	24	ns
			V_{CC}=5.0V; C_L=15pF	-	11	-	ns
			V_{CC}=6.0V	-	11	20	ns
transition time	t_t	see Figure 6[2]	V_{CC}=2.0V	-	19	75	ns
			V_{CC}=4.5V	-	7	15	ns
			V_{CC}=6.0V	-	6	13	ns
power dissipation capacitance	C_{PD}	per package; V_I=GND to V_{CC}[3]		-	18	-	pF

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_t is the same as t_{THL} and t_{TLH}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$P_D=C_{PD}\times V_{CC}^2\times f_i+\sum(C_L\times V_{CC}^2\times f_o)$ where:

f_i=input frequency in MHz; f_o=output frequency in MHz;

C_L=output load capacitance in pF;

V_{CC}=supply voltage in V;

$\sum(C_L\times V_{CC}^2\times f_o)$=sum of outputs.

3.3.5、AC Characteristics 2

(T_{amb}=-40℃ to +85℃, GND =0V, C_L=50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
propagation delay	t_{pd}	An, Bn to $Q_{A>B}$; An, Bn to $Q_{A<B}$; see Figure 6[1]	V_{CC}=2.0V	-	-	245	ns
			V_{CC}=4.5V	-	-	49	ns
			V_{CC}=6.0V	-	-	42	ns
		An, Bn to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	-	220	ns
			V_{CC}=4.5V	-	-	44	ns
			V_{CC}=6.0V	-	-	37	ns
		$I_{A=B}$ or $I_{A>B}$ to $Q_{A<B}$; $I_{A<B}$ or $I_{A=B}$ to $Q_{A>B}$; see Figure 6	V_{CC}=2.0V	-	-	175	ns
			V_{CC}=4.5V	-	-	35	ns
			V_{CC}=6.0V	-	-	30	ns
		$I_{A=B}$ to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	-	150	ns
			V_{CC}=4.5V	-	-	30	ns
			V_{CC}=6.0V	-	-	26	ns
transition time	t_t	see Figure 6[2]	V_{CC}=2.0V	-	-	95	ns
			V_{CC}=4.5V	-	-	19	ns
			V_{CC}=6.0V	-	-	16	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_t is the same as t_{THL} and t_{TLH}.

3.3.6、AC Characteristics 3

(T_{amb}=-40℃ to +125℃, GND =0V, C_L=50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
propagation delay	t_{pd}	An, Bn to $Q_{A>B}$; An, Bn to $Q_{A<B}$; see Figure 6[1]	V_{CC}=2.0V	-	-	295	ns
			V_{CC}=4.5V	-	-	59	ns
			V_{CC}=6.0V	-	-	50	ns
		An, Bn to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	-	265	ns
			V_{CC}=4.5V	-	-	53	ns
			V_{CC}=6.0V	-	-	45	ns
		$I_{A=B}$ or $I_{A>B}$ to $Q_{A<B}$; $I_{A<B}$ or $I_{A=B}$ to $Q_{A>B}$; see Figure 6	V_{CC}=2.0V	-	-	210	ns
			V_{CC}=4.5V	-	-	42	ns
			V_{CC}=6.0V	-	-	36	ns
		$I_{A=B}$ to $Q_{A=B}$; see Figure 6	V_{CC}=2.0V	-	-	180	ns
			V_{CC}=4.5V	-	-	36	ns
			V_{CC}=6.0V	-	-	31	ns
transition time	t_t	see Figure 6[2]	V_{CC}=2.0V	-	-	110	ns
			V_{CC}=4.5V	-	-	22	ns
			V_{CC}=6.0V	-	-	19	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_t is the same as t_{THL} and t_{TLH}.

4、Testing Circuit

4.1、AC Testing Circuit

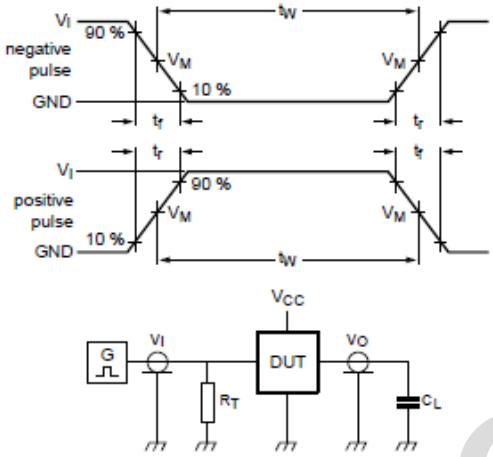


Figure 5. Test circuit for measuring switching times

Definitions for test circuit:

C_L=Load capacitance including jig and probe capacitance.

R_T=Termination resistance should be equal to the output impedance Z_o of the pulse generator.

4.2、AC Testing Waveforms

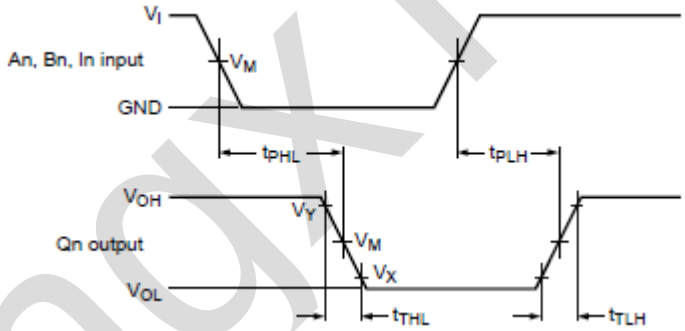


Figure 6. Word A inputs (An), word B inputs (Bn) and expansion inputs (In) to the outputs (Qn) propagation delays and the output transition times

4.3、Measurement Points

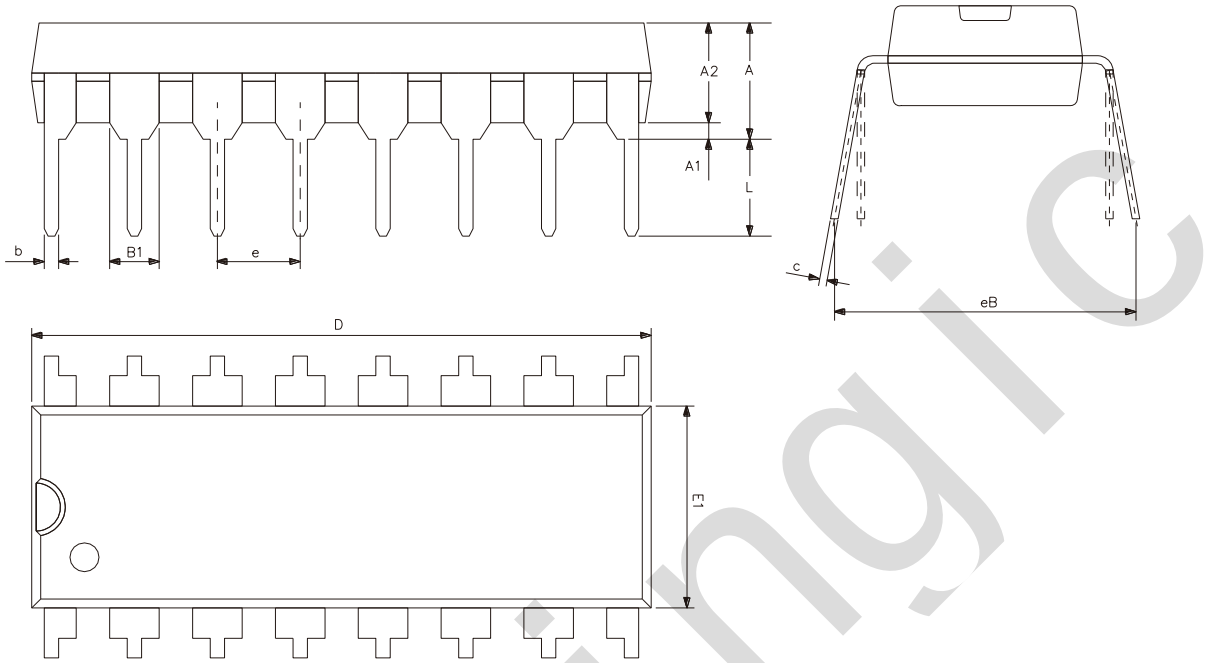
Input		Output		
V_I	**V_M**	**V_M**	**V_X**	**V_Y**
V_{CC}	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$0.1\times V_{CC}$	$0.9\times V_{CC}$

4.4、Test Data

Input		Load	Test
V_I	**t_r , t_f**	**C_L**	
V_{CC}	6ns	15pF, 50pF	t_{PHL}, t_{PLH}

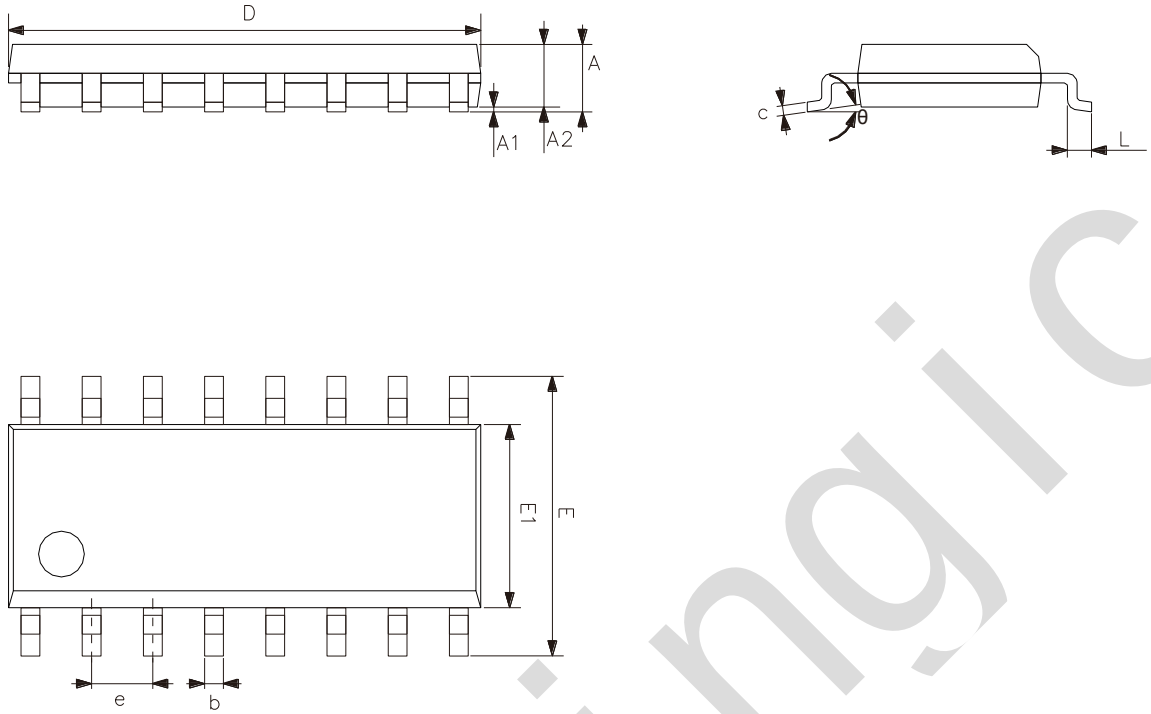
5、Package Information

5.1、DIP16



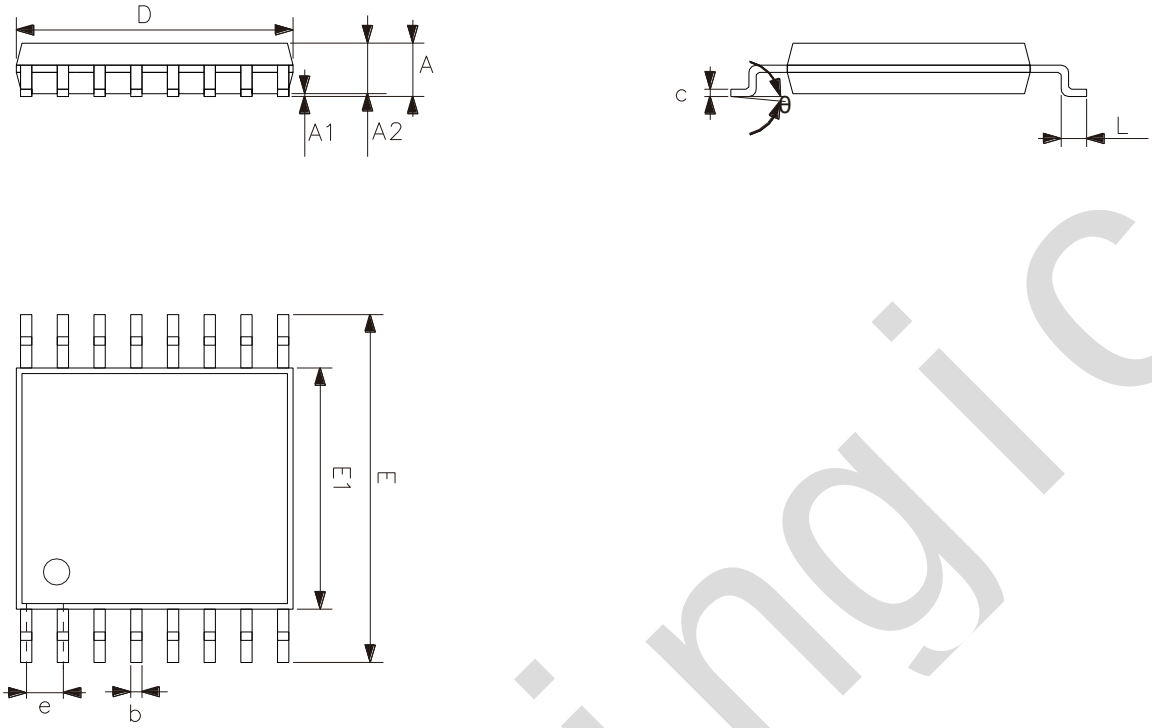
Symbol	Dimensions (mm)	
	Min.	Max.
A2	3.20	3.60
A1	0.51	-
A	3.60	5.33
L	3.00	3.60
b	0.36	0.56
B1	1.52	
D	18.80	19.94
E1	6.20	6.60
e	2.54	
c	0.20	0.36
eB	7.62	9.30

5.2、SOP16



Symbol	Dimensions (mm)	
	Min.	Max.
A	1.35	1.80
A1	0.10	0.25
A2	1.25	1.55
b	0.33	0.51
c	0.19	0.25
D	9.50	10.10
E	5.80	6.30
E1	3.70	4.10
e	1.27	
L	0.35	0.89
θ	0°	8°

5.3、TSSOP16



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E1	4.30	4.50
E	6.20	6.60
e	0.65	
L	0.45	0.75
θ	0°	8°

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○：Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×：Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notes

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